

BD233/235/237

Medium Power Linear and Switching Applications

- Complement to BD 234/236/238 respectively



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	: BD233	45
		: BD235	60
		: BD237	100
V_{CEO}	Collector-Emitter Voltage	: BD233	45
		: BD235	60
		: BD237	80
V_{CER}	Collector-Emitter Voltage	: BD233	45
		: BD235	60
		: BD237	100
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	2	A
I_{CP}	*Collector Current (Pulse)	6	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	25	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage	$I_C = 100\text{mA}, I_B = 0$: BD233	45		V
			: BD235	60		V
			: BD237	80		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 45\text{V}, I_E = 0$ $V_{CB} = 60\text{V}, I_E = 0$ $V_{CB} = 100\text{V}, I_E = 0$			100	μA
					100	μA
					100	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}, I_C = 0$			1	mA
h_{FE}	* DC Current Gain	$V_{CE} = 2\text{V}, I_C = 150\text{mA}$ $V_{CE} = 2\text{V}, I_C = 1\text{A}$	40 25			
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 1\text{A}, I_B = 0.1\text{A}$			0.6	V
$V_{BE(on)}$	* Base-Emitter ON Voltage	$V_{CE} = 2\text{V}, I_C = 1\text{A}$			1.3	V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 250\text{mA}$	3			MHz

* Pulse Test: PW=300 μs , duty Cycle=1.5% Pulsed

Typical Characteristics

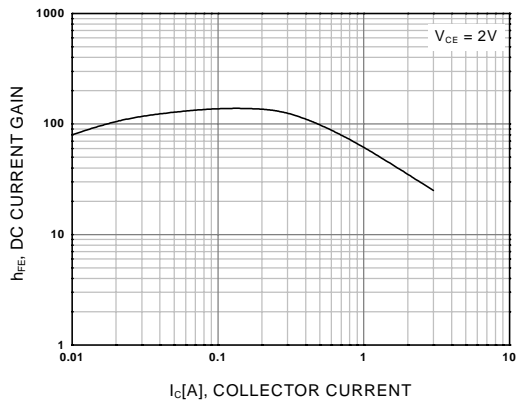


Figure 1. DC current Gain

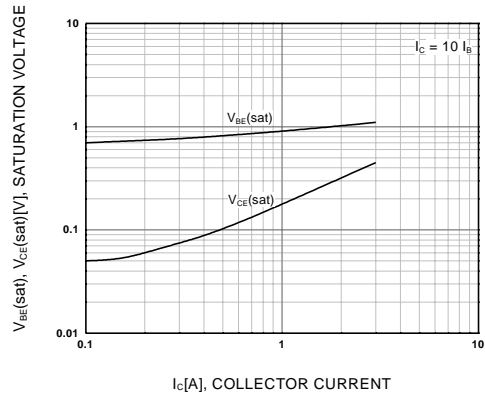


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

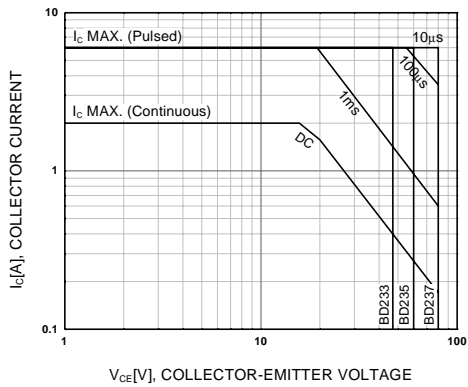


Figure 3. Safe Operating Area

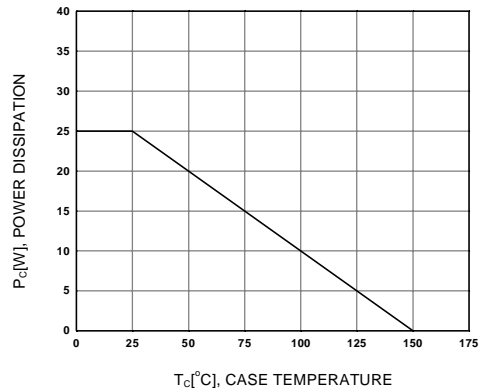


Figure 4. Power Derating

Package Demensions

TO-126

BD233/235/237



Dimensions in Millimeters

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
BD235STU	Full Production	\$0.18	TO-126	3	RAIL

* 1,000 piece Budgetary Pricing

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